

**Amendments to the Claims:**

There are no amendments to the claims. The following is a listing of the claims as currently pending:

Claims 1-38 (Canceled).

39. (Previously Presented): Integrated circuitry comprising:  
a substrate comprising a first conductive device component of a first type and being elongated in a first direction;  
a second conductive device component of the first type and being elongated in a second direction, the first and second conductive device components at least predominately comprising common conductive material and being present as part of a finished construction of the integrated circuitry; and  
the first and second conductive device components having different base widths in the finished circuitry construction, at least one of the first and second conductive device components being beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

40. (Original): The integrated circuitry of claim 39 wherein the first and second directions are parallel with one another.

41. (Original): The integrated circuitry of claim 39 wherein the first and second directions are not parallel with one another.

42. (Original): The integrated circuitry of claim 39 wherein the first and second conductive device components entirely comprise common conductive material in at least one cross section.

43. (Previously Presented): The integrated circuitry of claim 39 wherein both the first and the second conductive device components are beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

Claim 44 (Canceled).

45. (Previously Presented): The integrated circuitry of claim 39 wherein only one of the first and the second conductive device components is beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

46. (Previously Presented): Integrated circuitry comprising:  
a substrate comprising a first field effect transistor gate and being  
elongated in a first direction;  
a second field effect transistor gate and being elongated in a second  
direction, the first and second field effect transistor gates at least  
predominately comprising common conductive material and being present as  
part of a finished construction of the integrated circuitry; and  
the first and second field effect transistor gates having different base  
widths in the finished circuitry construction, at least one of the first and  
second field effect transistor gates being beveled from perpendicular to the  
substrate along at least a majority of its elongated length in its respective  
first or second direction in the finished circuitry construction.

47. (Previously Presented): The integrated circuitry of claim 46  
wherein the first and second directions are parallel with one another.

48. (Previously Presented): The integrated circuitry of claim 46  
wherein the first and second directions are not parallel with one another.

49. (Previously Presented): The integrated circuitry of claim 46  
wherein the first and second field effect transistor gates entirely comprise  
common conductive material in at least one cross section.

50. (Previously Presented): The integrated circuitry of claim 46 wherein both the first and the second field effect transistor gates are beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

51. (Previously Presented): The integrated circuitry of claim 46 wherein only one of the first and the second field effect transistor gates is beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

52. (Previously Presented): Integrated circuitry comprising:  
a substrate comprising a first conductive device component of a first type having a base and a top of first equal widths, and being elongated in a first direction;  
a second conductive device component of the first type having a base and a top of second equal widths, and being elongated in a second direction, the first and second conductive device components at least predominately comprising common conductive material and being present as part of a finished construction of the integrated circuitry; and  
the first and second widths being different in the finished circuitry construction, at least one of the first and second conductive device components being beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

53. (Previously Presented): The integrated circuitry of claim 52 wherein the first and second directions are parallel with one another.

54. (Previously Presented): The integrated circuitry of claim 52 wherein the first and second directions are not parallel with one another.

55. (Previously Presented): The integrated circuitry of claim 52 wherein the first and second conductive device components entirely comprise common conductive material in at least one cross section.

56. (Previously Presented): The integrated circuitry of claim 52 wherein both the first and the second conductive device components are beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

57. (Previously Presented): The integrated circuitry of claim 52 wherein only one of the first and the second conductive device components is beveled from perpendicular to the substrate along at least a majority of its elongated length in its respective first or second direction in the finished circuitry construction.

58. (Previously Presented): The integrated circuitry of claim 39 wherein the at least one conductive device component has opposing conductive sidewalls comprising respective substantially straight linear segments which are parallel with one another.

59. (Previously Presented): The integrated circuitry of claim 46 wherein the at least one field effect transistor gate has opposing conductive sidewalls comprising respective substantially straight linear segments which are parallel with one another.

60. (Previously Presented): The integrated circuitry of claim 52 wherein the at least one conductive device component has opposing conductive sidewalls comprising respective substantially straight linear segments which are parallel with one another.